

XN01115 (XN1115)

Silicon PNP epitaxial planar type

For switching/digital circuits

■ Features

- Two elements incorporated into one package
(Emitter-coupled transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

■ Basic Part Number

- UNR2115 (UN2115) × 2

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

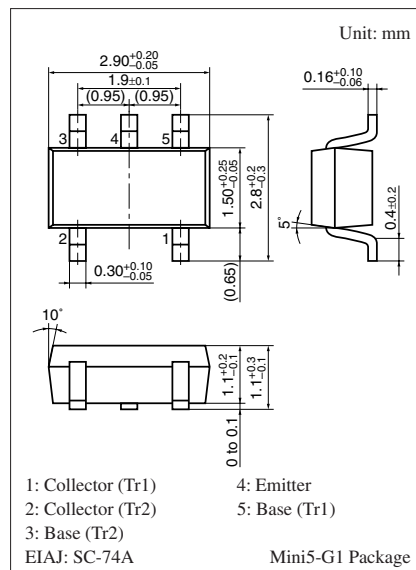
| Parameter | Symbol | Rating | Unit |
|---------------------------------------|-----------|-------------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | -50 | V |
| Collector-emitter voltage (Base open) | V_{CEO} | -50 | V |
| Collector current | I_C | -100 | mA |
| Total power dissipation | P_T | 300 | mW |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--|---|--|------|------|-------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_C = -10 \mu\text{A}$, $I_E = 0$ | -50 | | | V |
| Collector-emitter voltage (Base open) | V_{CEO} | $I_C = -2 \text{ mA}$, $I_B = 0$ | -50 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{CB} = -50 \text{ V}$, $I_E = 0$ | | | -0.1 | μA |
| Collector-emitter cutoff current (Base open) | I_{CEO} | $V_{CE} = -50 \text{ V}$, $I_B = 0$ | | | -0.5 | μA |
| Emitter-base cutoff current (Collector open) | I_{EBO} | $V_{EB} = -6 \text{ V}$, $I_C = 0$ | | | -0.01 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = -10 \text{ V}$, $I_C = -5 \text{ mA}$ | 160 | | 460 | — |
| h_{FE} Ratio * | $h_{FE(\text{Small})}$ $/h_{FE(\text{Large})}$ | $V_{CE} = -10 \text{ V}$, $I_C = -5 \text{ mA}$ | 0.50 | 0.99 | | — |
| Collector-emitter saturation voltage | $V_{CE(\text{sat})}$ | $I_C = -10 \text{ mA}$, $I_B = -0.3 \text{ mA}$ | | | -0.25 | V |
| Output voltage high-level | V_{OH} | $V_{CC} = -5 \text{ V}$, $V_B = -0.5 \text{ V}$, $R_L = 1 \text{ k}\Omega$ | -4.9 | | | V |
| Output voltage low-level | V_{OL} | $V_{CC} = -5 \text{ V}$, $V_B = -2.5 \text{ V}$, $R_L = 1 \text{ k}\Omega$ | | | -0.2 | V |
| Input resistance | R_I | | -30% | 10 | +30% | $\text{k}\Omega$ |
| Transition frequency | f_T | $V_{CB} = -10 \text{ V}$, $I_E = 1 \text{ mA}$, $f = 200 \text{ MHz}$ | | 80 | | MHz |

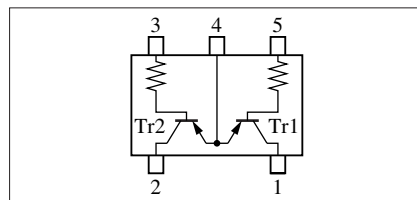
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Ratio between 2 elements

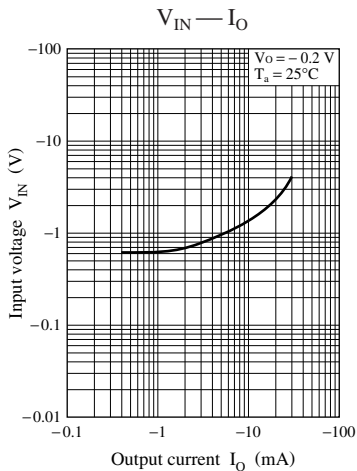
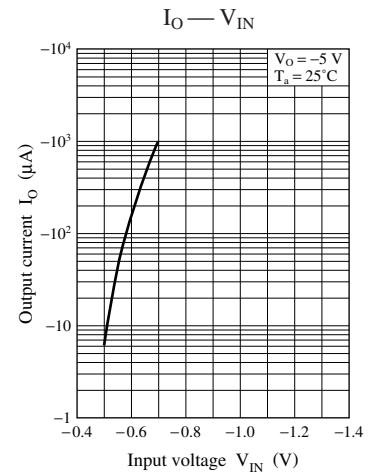
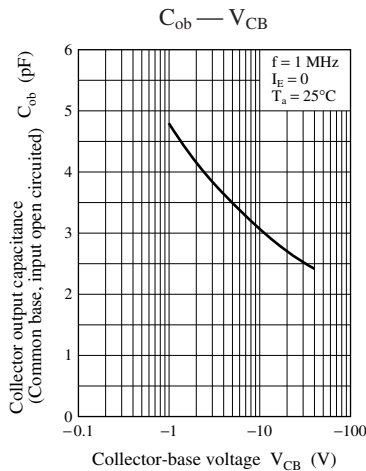
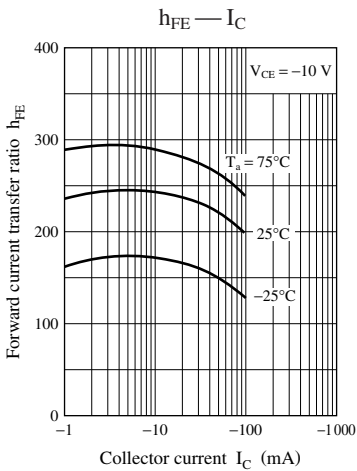
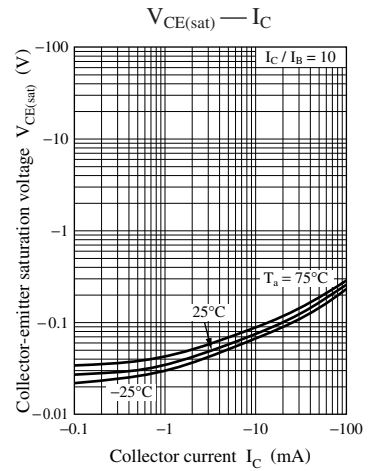
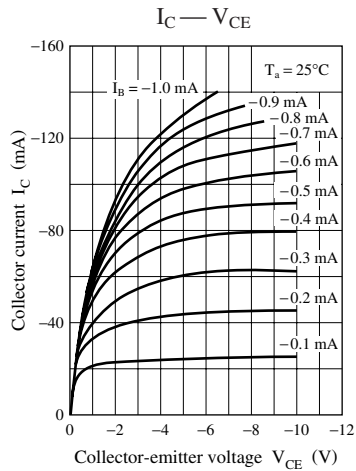
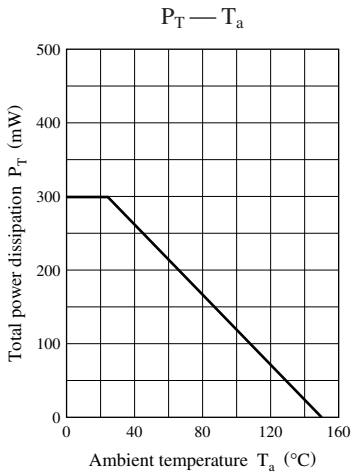


Marking Symbol: 7M

Internal Connection



Note) The part number in the parenthesis shows conventional part number.



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